# NSN 5961-01-541-1980

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-541-1980

#### **Overall Length:**

Between 0.240 inches and 0.260 inches

## **Terminal Length:**

0.500 inches

# **Overall Diameter:**

Between 0.350 inches and 0.370 inches

#### **End Application:**

Radar 3d e/f band, long range

#### Internal Configuration:

Junction contact-darlington connected

## Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-39

Internal Junction Configuration:

Pnp

#### **Mounting Method:**

Terminal

#### **Terminal Circle Diameter:**

Between 0.016 inches and 0.021 inches

#### Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

180.0 breakdown voltage, collector-to-base, emitter open

#### **Current Rating Per Characteristic:**

4.00 amperes all primaries

#### **Power Rating Per Characteristic:**

10.0 watts small-signal input power, common-collector preset

#### Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius ambient air

Shelf Life:

N/a

#### Unit Of Measure:

---

## Demilitarization:

No

#### Fiig:

A110a0